# **Equivalent circuit model of MPPC**

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### **GEIGER-APD**

**RS : Resistance of the entire APD during a discharge RQ :Quenching resistor CJ : Junction capacitance**

**typical values RS ~1 k, RQ~150 k, Cj~0.1 pf**

OFF

 $V_{BR}$ 

 $R_{S}$ 

*I*

 $R_{\rm Q}$ 

Cт

Diode (APD)

 $V_{BIAS}$ -Q/C<sub>i</sub>-iR<sub>Q</sub>=0  $V_{BIAS}$ - $V_{BR}$ - $(i-I)R_S$ -i $R_Q$ =0  $\tau_r = C_j \frac{(R_S R_Q)}{(R_S + R_Q)} \sim C_j R_S \ (\because R_Q \gg R_S) \ i = \frac{V_{BLAS} - V_{BR}}{R_S + R_Q} (1 - e^{-t/\tau_r}) \sim \frac{V_{BLAS} - V_{BR}}{R_Q} (1 - e^{-t/\tau_r})$  $\tau_r = C_i R_O$  $\sim$ (V<sub>BIAS</sub> – V<sub>BR</sub>)/R<sub>O</sub> i *i-I* $i_{\rm max}$ **VBIAS**  $\sim$ [1-exp(-t/R<sub>s</sub>×C<sub>J</sub>)]  $V_D$  $\sim$ exp(-t/R<sub>Q</sub>×C<sub>J</sub>)

 $t_i$   $t_{max}$ 

By Kirchhof's current law

**Equivalent circuit of MPPC's single GAPD**

**Current flowing through the APD as a function of time**



"ready"

time

"ready"

## **STRUCTURE OF THE MPPC**

#### **Structure of the MPPC**

**Equivalent circuit of the MPPC** 







# **EQUIVALENT CIRCUIT OF THE MPPC**

#### **Equivalent circuit of the MPPC N: total # of pixels of the MPPC n: # of fired pixels of the MPPC fired pixels(n pixels)** Ra Ra Ra Ra Rq/(N-n) Rg/n *nI… …* Vbr nCj  $(N-n)Cj$  $\sum$  *Rs<sub>I</sub>*  $nI_1$   $\left[\begin{array}{c|c} mI_2 & f(N-n)I' \end{array}\right]$ **RS : Resistance of the entire APD RQ :Quenching resistor** HV **CJ : Junction capacitance** *i*

**R1 and R2 : series resistors in circuit (Let R= R1+R2)**



HV

## **EQUIVALENT CIRCUIT OF THE MPPC**

#### **Equivalent circuit of MPPC**



**RS : Resistance of the entire APD RQ :Quenching resistor CJ : Junction capacitance**

**N: total # of pixels, n: # of fired pixels R1 and R2 : series resistors in circuit (Let R= R1+R2)**

By Kirchhof's current law i=nI+(N-n)I',  $I = I_1 + I_2$  $V_{BIAS} - V_{BR} - iR - I_1 R_S - I R_Q = 0$  $V_{BIAS} - iR - Q/C_i - IR_Q = 0$  $V_{BIAS} - iR - Q'/C_i - I'R_Q = 0$ 

$$
\begin{aligned}\n\text{Leading edge} \\
\tau_r &= C_j R_S \\
i &= \frac{n(V_{BIAS} - V_{BR})}{nR + R_S + R_Q} \left( 1 - e^{-t/\tau_r} \right) \sim \frac{n(V_{BIAS} - V_{BR})}{R_Q} \left( 1 - e^{-t/\tau_r} \right) \\
I &= \frac{n(V_{BIAS} - V_{BR})}{nR + R_S + R_Q} \sim \frac{n(V_{BIAS} - V_{BR})}{R_Q}\n\end{aligned}
$$

Trailing edge  $\tau_t = C_j(R_Q + NR)$ 



## **PREVIOUS TEST CONDITION**

#### **MPPC has 16 channels**



- ➤ **Sixteen Channels were connected in parallel**
- ➤ **Single DC power applied same voltages for all channels**
- ➤ **Current outputs of every channel's were gathered**



## **MPPCS IN PARALLEL CONNECTION**

#### **Equivalent circuit**



**R<sub>S</sub>**: Resistance of the entire APD **RQ :Quenching resistor CJ : Junction capacitance**

**N: total # of pixels, n: # of fired pixels R1 and R2 : series resistors in circuit (Let R= R1+R2)**

**Assume that number of 'a' MPPCs are connected in parallel Only one thing is different from single MPPC, N->aN** 

**For the leading edge, all parameters and values still remain same** 

$$
\begin{aligned}\n\text{Leading edge} \\
\tau_r &= C_j R_S \\
i &= \frac{n(V_{BIAS} - V_{BR})}{nR + R_S + R_Q} \left(1 - e^{-t/\tau_r}\right) \sim \frac{n(V_{BIAS} - V_{BR})}{R_Q} \left(1 - e^{-t/\tau_r}\right) \\
I &= \frac{n(V_{BIAS} - V_{BR})}{nR + R_S + R_Q} \sim \frac{n(V_{BIAS} - V_{BR})}{R_Q}\n\end{aligned}
$$

**Time constant of fall time has a term promotional to 'a' So, tailing edge become longer**

$$
\tau_t = C_j R_Q + a \times C_j N R
$$



## **REFERENCE OF MULTI-MPPC BIASING**

#### **MEG Collaboration's test results**

*Kaneko, D., Performance of UV-sensitive MPPC for liquid xenon detector in MEG experiment,* 

*DOI:10.1109/NSSMIC.2013.6829484.*





Fig. 10. Connection of 4 MPPCs, 4-parallel, 2-series 2-parallel and 4-series correspond (a), (b) and (c) respectively.



### **MPPCS IN SERIES CONNECTION**

#### **Equivalent circuit**



**RS : Resistance of the entire APD RQ :Quenching resistor CJ : Junction capacitance**

**N: total # of pixels, n: # of fired pixels R1 and R2 : series resistors in circuit (Let R= R1+R2)**

**Load of the other MPPCs Bias voltage should become larger in proportional to the number of MPPCs**

**Assume the condition that photons are firing only one MPPC (the other cases can be described as a superposition of above situations)**

**Because of load of additional MPPCs, it is hard to get exact solutions. With another assumption dI/dt = 0, rising edge shape remains almost same But there is a small voltage drop occur through series MPPCs**

$$
_{-\tau r}^{\tau}\sim C_{j}R_{S}
$$

**For the tailing edge, time constant become small, So, signal also become shorter**

$$
\tau_t = C_j R_Q + C_j N R/a
$$

